## NSN 5961-01-146-1991

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View Online at https://aerobasegroup.com/nsn/5961-01-146-1991
Inclosure Material:
Metal
Overall Length:
1.195 inches
Overall Diameter:
2.150 inches
End Application:
Tas mk 23
Internal Configuration:
Junction contact
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
5.0 peak negative gate voltage
Current Rating Per Characteristic:
4.00 amperes forward current, total rms of standard range
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector peak
Special Features:
${\small 2\ remove able\ leads\ included;\ junction\ pattern\ arrangement:\ npnp}\\$
Terminal Type And Quantity:
1 case and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0